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Switching charge transfer process of carbon nitride and bismuth vanadate by anchoring silver nanoparticle toward cocatalyst free water reduction

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G R A P H I C A L A B S T R A C T

A ternary catalyst was constructed which exhibit superior H₂ production rate with co-catalyst free under visible light irradiation.

A R T I C L E I N F O

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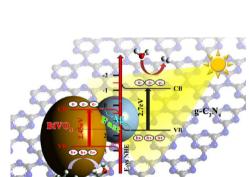
ABSTRACT

With the aim of exploring and modulating the interfacial charge kinetics, a ternary g-C₃N₄/Ag/BiVO₄ was constructed with excellent photocatalytic performance and preferable stability toward H₂ evolution in absence of cocatalyst. Both density functional theory (DFT) and experimental results implied that the type II g-C₃N₄/BiVO₄ composite can be switched to Z-scheme via Ag nanoparticles as the electron shuttle. The optimal photocatalytic H₂ yield rate achieved for g-C₃N₄/Ag/BiVO₄ was 57.4 µmol·g⁻¹·h⁻¹, being far surpassed the H₂ harvest rate of g-C₃N₄/BiVO₄, Ag/g-C₃N₄ and g-C₃N₄, which is 2.9, 14.8 and 1.7 µmol·g⁻¹·h⁻¹, respectively. The apparent quantum efficiency of g-C₃N₄/Ag/BiVO₄ well preserved over 5 runs in 50 h. The improved H₂ production performance is considered as the consequence of promoted segregation of photoexcited charge carriers and SPR effects of Ag nanoparticles. In combination with photocurrent measurement, examination of active species and DFT calculation, it is found that Ag nanoparticles as an electron band of BiVO₄ will quickly assemble with the photo-induced holes from valence band of g-C₃N₄, leaving electrons in the conduction band of g-C₃N₄ and holes in valence band of BiVO₄ that could greatly enhance the charge separation efficiency.

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1. Introduction

Semiconductor photocatalysis for hydrogen production provides an important environmental benign strategy toward sustainable energy conversion [1-5]. To meet the flexible industrial processing ability, the development of efficient photocatalytic system with high solar energy conversion efficiency is demanded. However, the bottlenecks of photocatalysts, such as low visible light absorption and poor quantum efficiency, are still of hindrance for practical applications, in spite of great efforts have been dedicated, including band gap engineering, surface modification and semiconductor heterojunction [6-8]. Recently, heterostructured materials by combining two semiconductors with band alignment are found effective photocatalysts to improve catalytic activity. However, traditional heterojunctions meet weakened reduction and oxidation ability of photoinduced charge carriers, which fall short of the requirement of high redox potential of H^+/H_2 for hydrogen production [9]. The Z-scheme photocatalytic systems possessing excellent redox driving force and charge separation efficiency have garnered much research attention for enhanced photocatalytic performance [10,11]. Using a redox shuttle or electron mediator, a Z-scheme charge transfer can be modulated to achieve spatial isolation of photoinduced charge carriers for more positive valence band potential and more negative conduction band potential [12]. Hence, it's highly desirable to modulate the interfacial charge kinetics to develop Z-scheme photocatalysts for improving photocatalytic activity.

Among widely investigated oxides, nitrides, and oxyhalides, graphite-like carbon nitrides carries a more negative conduction band potential (\sim -1.1 V vs. NHE) with a strong redox capability, which has been widely applied for photocatalytic hydrogen production [13-16]. However, it still has some drawbacks, like the high rate of recombination for photoexcited charge carriers and strong reliance on co-catalysts. Building g-C₃N₄ based heterostructure can provide an effective way for overcoming these disadvantages. A great deal of g-C₃N₄ based Z-scheme heterojunctions, including g-C₃N₄/TiO₂, g-C₃N₄/SnS₂, g-C₃N₄/Ag₃PO₄, and so forth were developed [17–20]. For instance, the nanojunction of g-C₃N₄/TiO₂ resulted in the constitution of a settled electric field that can gather photoinduced electrons and holes in diverse face region and prolong the longevity about charge carriers with strong reductive and oxidative ability [10]. Since the band gap construction of $g-C_3N_4$ matches well with that of BiVO₄, the junction of $g-C_3N_4$ and BiVO₄ may predict spatial charge separation and improved photocatalytic reactivity. However, it is still controversial that the charge migration between g-C₃N₄ and BiVO₄ demonstrates type II or Z-scheme transfer process [21–25]. Moreover, binary component heterojunctions still have drawbacks of slower charge transfer rate and inefficient charge separation ratio. To solve these problems, semiconductor-metal-semiconductor (S-M-S) ternary component systems have been developed. As a model S-M-S system, CdS-Au-TiO₂ possessed a fast vertical electron transfer of $CdS \rightarrow Au \rightarrow TiO_2$, resulting in high photocatalytic activity toward methylviologen (MV²⁺) reduction, which improved by a factor of 1.6, 1.8 and 2.3 times in comparison to Au/TiO₂, CdS/TiO₂ and bare TiO₂ [9,26]. Usually, noble metallic nanoparticles were adopted as the electron shuttle to construct S-M-S system for promotion of photoreactivity. Having these in mind, the construction of ternary g-C₃N₄-M-BiVO₄ system predicts efficient charge separation and the subsequent improved photocatalytic performance. Though some studies of g-C₃N₄-M-BiVO₄ photocatalytic systems have been reported about degradating organic pollutants and oxidizing NO [8,12], it is still highly necessary to explore the interfacial charge kinetics and its application in water reduction.

In this work, using $g-C_3N_4/Ag/BiVO_4$ ternary photocatalytic system as model, we found that the type II $g-C_3N_4/BiVO_4$ composite

can be switched to Z-scheme via Ag nanoparticles as electron shuttle. The coupling effects of $g-C_3N_4$ and $BiVO_4$ nanoparticles with Ag modification were systematically investigated in attempt to shed light on the interfacial charge kinetics and possible reasons for significant enhancement of photocatalytic performance toward hydrogen evolution.

2. Experiment

2.1. Sample synthesis

Synthesis of $Ag/g-C_3N_4$ photocatalyst: All reagents used were of analytical grade purity none of re-distillation. Water used was ultrapure water. The synthetic procedure for Ag/g-C₃N₄ catalyst can be briefly depicted as follows: g-C₃N₄ was obtained by calcining melamine. In a typical synthesis, 2.38 g melamine (CP, Sinopharm Group chemical reagent Co. Ltd) was ground for 30 min and placed in a semiclosed alumina crucible with a lid and heated at a speed of 5 °C/min to 550 °C for 4 h, cooling and regrinding to obtain yellow powder of g-C₃N₄, and the g-C₃N₄ sample was used directly without any further washing treatment. For the second step, different quality (1.00 g, 0.98 g, 0.96 g, 0.94 g, 0.92 g, 0.90 g) of $g-C_3N_4$ was blended with the different quality (0 g, 0.03 g, 0.06 g, 0.09 g, 0.12 g, 0.15 g) of AgNO₃ (AR, Wind ship in tianjin chemical reagent Co. Ltd), and ground for 30 min, then kept at 550 °C for 4 h. Finally, they were allowed to cool to ambient temperature and reground to reach different Ag/g-C₃N₄ composite photocatalyst (Ag mass ratios 0%, 2%, 4%, 6%, 8%, 10%). They were marked as g-C₃N₄, AC1, AC2, AC3, AC4 and AC5, respectively.

Synthesis of $BiVO_4$ photocatalyst: 5 mmol $Bi(NO_3)_3 \cdot 5H_2O$ (AR, Wind ship in tianjin chemical reagent Co. Ltd), was dissolved in 20 mL nitric acid (2 M) to obtain solution A. Meanwhile, 5 mmol of NH₄VO₃ (AR, Adamas Reagent Co. Ltd) was dissolved in 10 mL NaOH solution (2 M) to acquire solution B and was injected drop by drop into solution A under intense stirring to achieve a steady suspension. The suspension liquid was regulated to adjust pH value of 7 using 1 M NaOH solution with energetic stirring for 30 min. Then it was poured into 100 mL Teflon-lined stainless steel autoclaves and reacted at 180 °C for 12 h. The achieved outcome was washed with ultra-pure grade water for several times and maintained at 60 °C to obtain BiVO₄.

Synthesis of g-C₃N₄/Ag/BiVO₄ photocatalyst: Different quality of Ag/g-C₃N₄ (with Ag mass ratio of 8%) was mixed with the different quality of the BiVO₄ to synthesize the ternary g-C₃N₄/Ag/BiVO₄ heterojunction (with mass ratios of 9:1, 7:3, 5:5, 3:7, 1:9). The compound was calcined at 400 °C at a speed of 5 °C /min for 4 h to acquire different ratio compound semiconductor photocatalytic materials of g-C₃N₄/Ag/BiVO₄. They were marked as ACB1, ACB2, ACB3, ACB4 and ACB5, respectively. For the purpose of comparison, the g-C₃N₄/BiVO₄ (with mass ratio of 9:1) photocatalyst was prepared and marked as CB1.

2.2. Sample characteristic analysis

Phase purity of all catalysts was measured by X-ray diffraction (XRD) using Panalytical X-ray diffractometer with a copper target at 40 kV and 40 mA. The diffraction patterns were kept track in the scope of $2\theta = 5-80^{\circ}$ at a scan speed of 1° min⁻¹. Particle dimension and morphologies of the catalyst were tested using transmission electron microscopy (TEM) on a FEI TECNAI F20 S-Twin with an acceleration voltage of 200 kV. The Fourier transform infrared (FT-IR) spectra of all catalysts were taken on a Perkin–Elmer IR spectrophotometer at a resolution of 4 cm⁻¹ using the KBr pellet skill. The UV–Vis absorption spectra were recorded on a UVIKON XL/XS diffuse reflectance spectrophotometer in the wavelength

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